

Data Sheet October 1998 File Number 2257.1

9.6A, 500V, 0.600 Ohm, N-Channel Power MOSFET

IThis is an N-Channel enhancement mode silicon gate power field effect transistor designed for applications such as switching regulators, switching converters, motor drivers, relay drivers, and drivers for high power bipolar switching transistors requiring high speed and low gate drive power. This type can be operated directly from integrated circuits.

Formerly developmental type TA17435.

Ordering Information

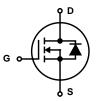
| PART NUMBER | PACKAGE | BRAND |
|-------------|----------|-------|
| BUZ45 | TO-204AA | BUZ45 |

NOTE: When ordering, use the entire part number.

Features

- 9.6A, 500V
- $r_{DS(ON)} = 0.600\Omega$
- SOA is Power Dissipation Limited
- · Nanosecond Switching Speeds
- · Linear Transfer Characteristics
- · High Input Impedance
- · Majority Carrier Device

Symbol



Packaging

JEDEC TO-204AA

